

/ Descriptions

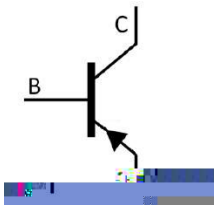
TO-92 PNP Silicon PNP transistor in a TO-92 Plastic Package.

/ Features

Low saturation voltage, large current capacity and wide ASO.

/ Applications

Power supplies, relay drivers, lamp drivers, strobes.

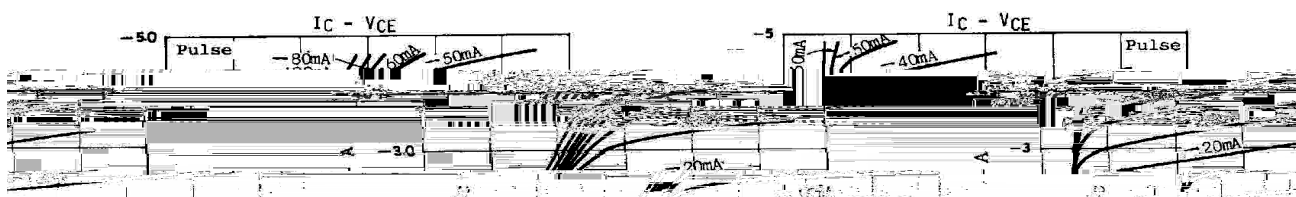


PIN1 Base PIN 2 Collector PIN 3 Emitter

/ hFE Classifications & Marking

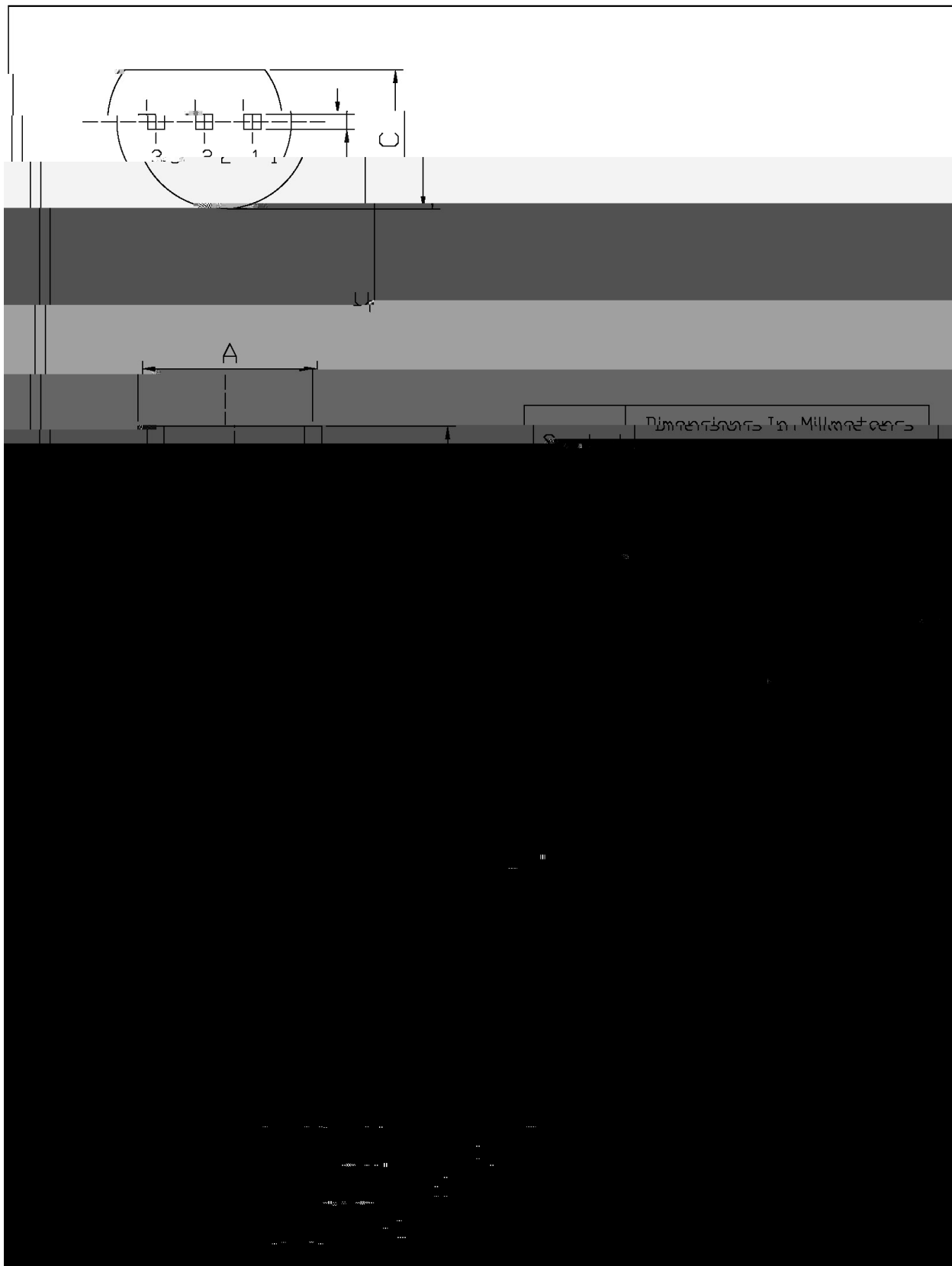
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-20	V
Collector to Emitter Voltage	V_{CEO}	-10	V
Emitter to Base Voltage	V_{EBO}	-7.0	V
Collector Current - Continuous	I_C	-2.5	A
Collector Current – Continuous(Pulse)	I_{CP}	-5.0	A
Collector Power Dissipation	P_C	750	mW

/ Electrical Characteristic Curve

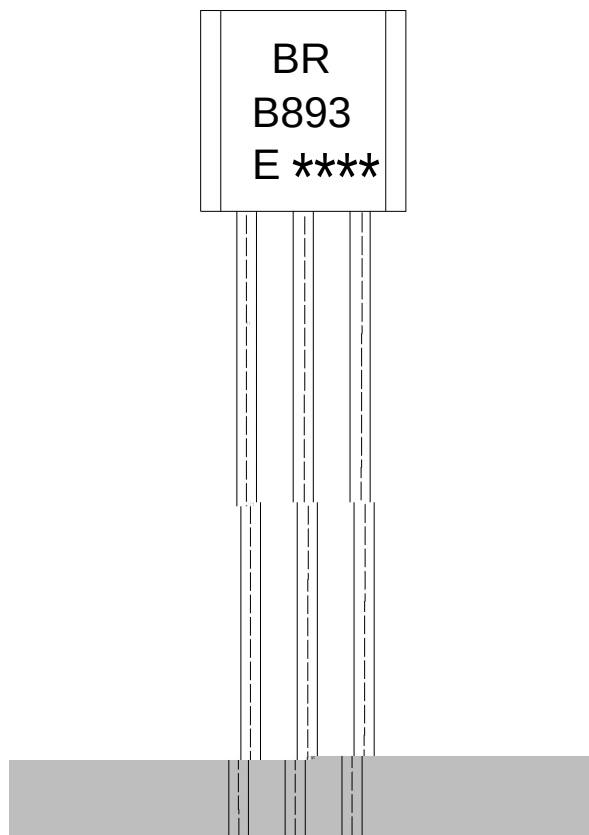


T O - 92

Unit: mm mm



/ Marking Instructions



BR:

B893

E: h_{FE}

Note:

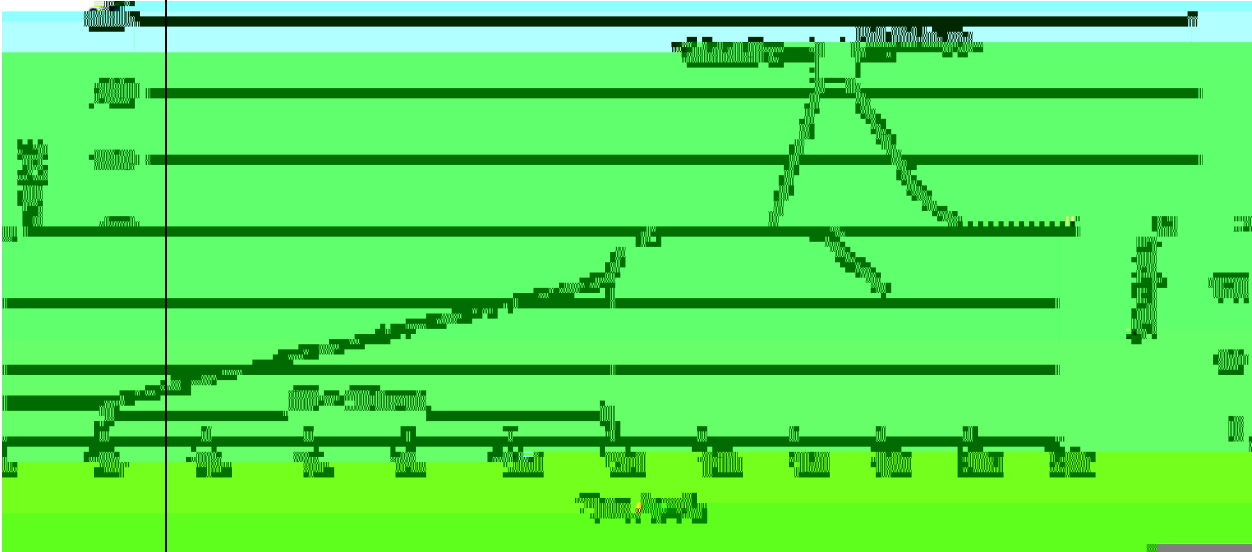
BR: Company Code.

B893: Product Type.

E: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150 60 90sec;

255±5 5±0.5sec;

2 10 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

/ AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	Units/tape 只/纸带	Tape/Inner Box 纸带/盒	Rows/Inner Box 纸带层/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-92	3,000	1	120	10	30,000	328×230×42	小箱 480×346×235, 大箱 547×407×268